

#### 40V P-CHANNEL ENHANCEMENT MODE MOSFET

### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> max	I <sub>D</sub> max T <sub>A</sub> = +25°C
40) /	80mΩ @ V <sub>GS</sub> = -10V	-3.4A
-40V	100mΩ @ V <sub>GS</sub> = -4.5V	-3.0A

### **Description and Applications**

This MOSFET is designed to meet the stringent requirements of Automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Battery Charging
- Power Management Functions
- DC-DC Converters
- Portable Power Adaptors

# **Features and Benefits**

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- PPAP Capable (Note 4)

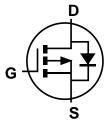
#### **Mechanical Data**

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
   Solderable per MIL-STD-202, Method 208 <sup>(3)</sup>
- Terminals Connections: See Diagram Below
- Weight: 0.008 grams (Approximate)

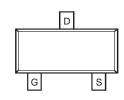
SOT23







Internal Schematic



Top View

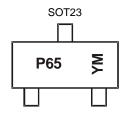
#### Ordering Information (Note 5)

Part Number	Case	Packaging
DMP4065SQ-7	SOT23	3,000/Tape & Reel
DMP4065SQ-13	SOT23	10,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/product\_compliance\_definitions.html.
- 5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**



P65 = Product Type Marking Code YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: E = 2017) M = Month (ex: 9 = September)

Date Code Kev

Year	201	4	2015		2016	20	17	2018		2019	2	2020
Code	В		С		D	[	Ε	F		G		Н
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Drain-Source Voltage		$V_{DSS}$	-40	V	
Gate-Source Voltage	$V_{GSS}$	±20	V		
Continuous Drain Current (Note 6) V <sub>GS</sub> = -10V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	l <sub>D</sub>	-2.4 -1.9	А
IICONTINUOUS Drain Current (Note /) Voc = -10V I - 1		$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I <sub>D</sub>	-3.4 -2.7	Α
Pulsed Drain Current			I <sub>DM</sub>	-20	Α
Avalanche Current, L = 0.1mH		I <sub>AS</sub>	-14	Α	
Avalanche Energy, L = 0.1mH	•	E <sub>AS</sub>	9.8	mJ	

# **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	$P_{D}$	0.72	W
Thermal Resistance, Junction to Ambient @T <sub>A</sub> = +25°C (Note 6)	$R_{ heta JA}$	171	°C/W
Power Dissipation (Note 7)	$P_{D}$	1.4	W
Thermal Resistance, Junction to Ambient @T <sub>A</sub> = +25°C (Note 6)	$R_{ heta JA}$	90	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)				•		•
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-40	_	_	V	$V_{GS} = 0V, I_D = -250\mu A$
Zero Gate Voltage Drain Current T <sub>J</sub> = +25°C	I <sub>DSS</sub>	_	_	-1.0	μΑ	$V_{DS} = -40V, V_{GS} = 0V$
Gate-Source Leakage	I <sub>GSS</sub>	_	_	±100	nA	$V_{GS} = \pm 20V$ , $V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	-1.0	_	-3.0	V	$V_{DS} = V_{GS}$ , $I_D = -250\mu A$
Static Drain-Source On-Resistance	D		64	80	mΩ	$V_{GS} = -10V, I_D = -4.2A$
Static Dialit-Source Off-Resistance	R <sub>DS(ON)</sub>		85	100	11122	$V_{GS} = -4.5V$ , $I_{D} = -3.3A$
Diode Forward Voltage	$V_{SD}$	_	-0.7	-1.2	<b>V</b>	$V_{GS} = 0V$ , $I_S = -1A$
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	C <sub>iss</sub>	_	587	_	pF	
Output Capacitance	Coss	_	88	_	рF	$V_{DS} = -20V, V_{GS} = 0V,$ - f = 1.0MHz
Reverse Transfer Capacitance	$C_{rss}$	_	40	_	pF	1 = 1.01/11/12
Gate Resistance	Rg	_	14.4	_	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$
Total Gate Charge (V <sub>GS</sub> = -4.5V)	$Q_{g}$	_	6.1	_	nC	
Total Gate Charge (V <sub>GS</sub> = -10V)	$Q_g$	_	12.2	_	nC	$V_{DS} = -20V, I_{D} = -4.2A$
Gate-Source Charge	$Q_{gs}$	_	1.8	_	nC	$V_{DS} = -20V, I_{D} = -4.2A$
Gate-Drain Charge	$Q_{gd}$	_	2.4	_	nC	
Turn-On Delay Time	t <sub>D(ON)</sub>	_	3.6	_	ns	
Turn-On Rise Time	t <sub>R</sub>	_	2.9	_	ns	$V_{DD} = -15V, V_{GS} = -10V,$
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	36.3	_	ns	$I_D = -1.0A, R_G = 6\Omega$
Turn-Off Fall Time	t <sub>F</sub>	_	15.3	_	ns	

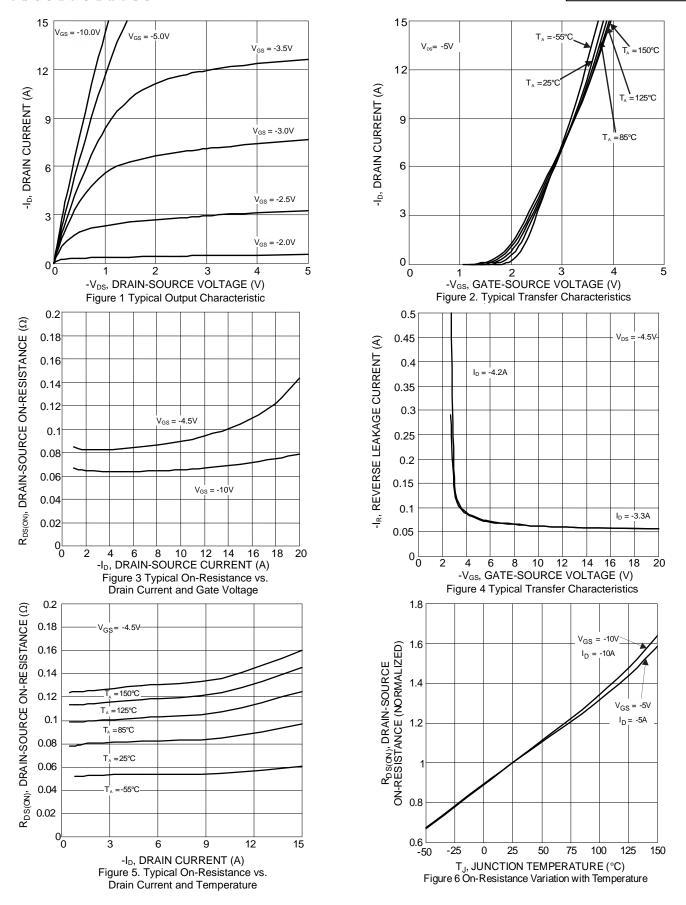
Notes: 6. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

<sup>7.</sup> Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.

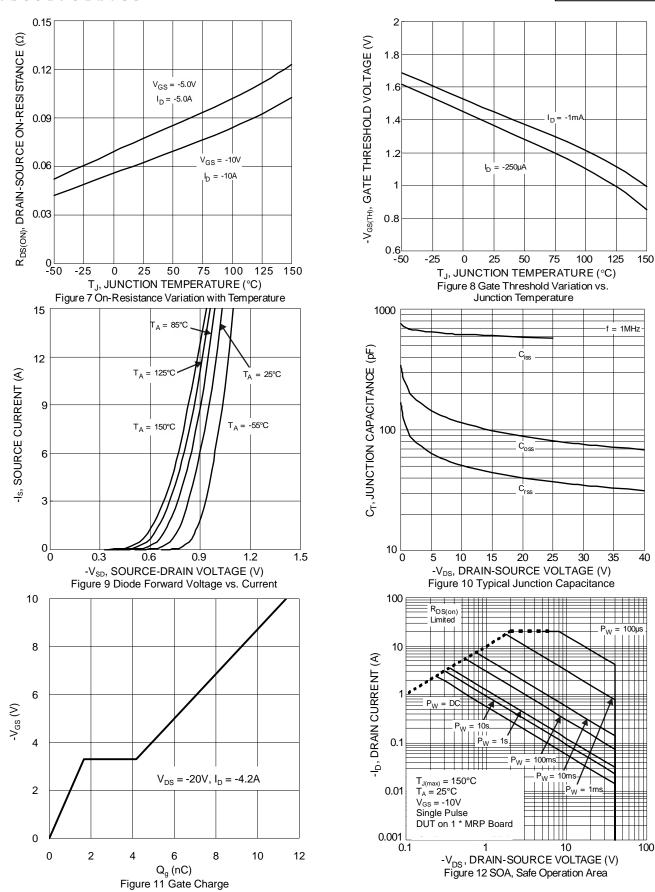
<sup>8.</sup> Short duration pulse test used to minimize self-heating effect.

<sup>9.</sup> Guaranteed by design. Not subject to product testing.

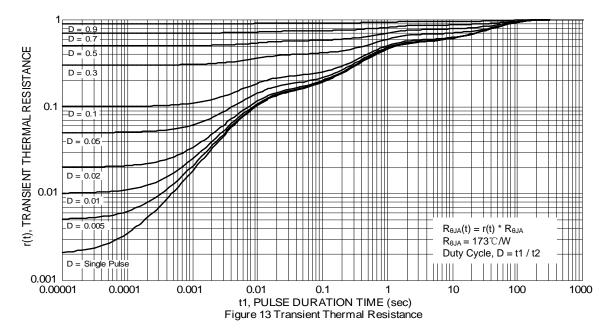










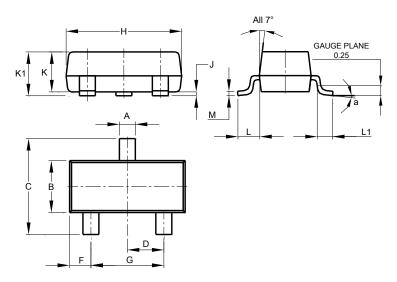




# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23

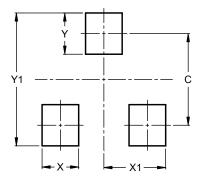


SOT23							
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
С	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
Н	2.80	3.00	2.90				
J	0.013	0.10	0.05				
K	0.890	1.00	0.975				
K1	0.903	1.10	1.025				
L	0.45	0.61	0.55				
L1	0.25	0.55	0.40				
М	0.085	0.150	0.110				
а	0°	8°					
All Dimensions in mm							

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Υ	0.9
Y1	2.9



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